TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

# TLP3041(S),TLP3042(S),TLP3043(S)

OFFICE MACHINE HOUSEHOLD USE EQUIPMENT TRIAC DRIVER SOLID STATE RELAY

The TOSHIBA TLP3041 (S), TLP3042 (S), TLP3043 (S) consist of a zero voltage crossing turn-on photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

• Peak Off-State Voltage : 400 V (min)

• Trigger LED Current : 15 mA (max) (TLP3041(S))

10 mA (max) (TLP3042(S))

5 mA (max) (TLP3043(S))

On-State Current : 100 mA (max)
 Isolation Voltage : 5000 Vrms (min)

• UL Recognized : UL1577, File No. E67349

• cUL approved :CSA Component Acceptance Service

No. 5A, File No.E67349

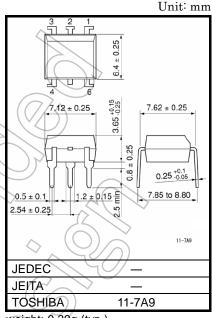
• Option (D4) type VDE approved: EN60747-5-5,

EN60065, EN60950-1(Note 1) EN62368-1(Pending) (Note1)

(Note 1):When a VDE approved type is needed, please designate the "Option (D4)"

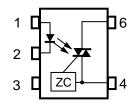
Construction mechanical rating

	7.62 mm pitch Standard Type	10.16 mm pitch TLPxxxxF Type
Creepage Distance	7.0 mm (Min)	8.0 mm (Min)
Clearance	7.0 mm (Min)	8.0 mm (Min)
Insulation Thickness	0.5 mm (Min)	0.5 mm (Min)



weight: 0.39g (typ.)

## Pin Configuration (top view)



- 1: Anode
- 2: Cathode
- 3: N.C.
- 4:Terminal 1
- 6:Terminal 2

ZC:Zero-cross Circuit



#### **Absolute Maximum Ratings (Ta = 25°C)**

Forward Current IF 50 r Forward Current Derating $\Delta I_F / {}^{\circ}C$ $-0.7$ m/A  Peak Forward Current $(100\mu s \text{ pulse}, 100 \text{pps})$ IFP 1  Reverse Voltage VR 5	JNIT mA A / °C A V
Forward Current Derating (Ta $\geq$ 53°C) $\Delta$ IF / °C $-0.7$ mA  Peak Forward Current (100 $\mu$ s pulse, 100pps) IFP 1  Reverse Voltage VR 5	A / °C
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	A
(100 $\mu$ s pulse, 100pps)  Reverse Voltage  VR  5	
	V
Power Dissipation PD 100 n	
	mW
Power Dissipation Denating $\Delta P_D / ^{\circ}C$ -1.0 mV (Ta $\geq 25^{\circ}C$ )	W / °C
Junction Temperature T <sub>j</sub> 125	°C
Off-State Output Terminal Voltage V <sub>DRM</sub> 400	V
On-Stage RMS Ta = 25°C 100	
Current Ta = 70°C IT(RMS) 50	mA
	A/°C
Peak On-Stage Current (100 µs pulse, 120 pps)  Peak Nonrepetitive Surge	A <
Peak Nonrepetitive Surge Current (P <sub>W</sub> = 10ms)	A
Power Dissipation PD 300 n	mW
Power Dissipation Denating (Ta $\geq$ 25°C) $\Delta P_D$ / °C $-4.0$ mV	W/°C
Junction Temperature T <sub>j</sub> 115	-c ( ( )
Storage Temperature Range T <sub>stg</sub> –55 to 150	°C
Operating Temperature Range Topr -40 to 100	°C
Lead Soldering Temperature (10s) T <sub>SOI</sub> 260	°C /
Total Package Power Dissipation PT 330 r	mW
Total Package Power Dissipation Derating (Ta $\geq$ 25°C) $\Delta P_{\overline{1}}/^{\circ}C$ $-4.4$ mV	N / °C
Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note 1) BVs 5000 V	/rms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4 and 6 shorted together.

#### **Recommended Operating Conditions**

CHARACTERISTIC	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Voltage	VAC	_	_	120	Vac
Forward Current	l <sub>F</sub> *	15	20	25	mA
Peak On-Stage Current	I <sub>TP</sub>	_	_	1	Α
Operating Temperature	T <sub>opr</sub>	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

\*: In the case of TLP3042



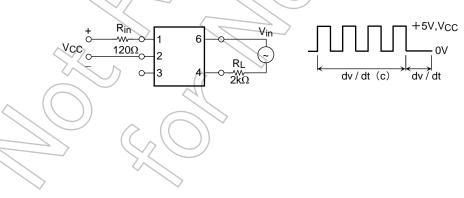
### Individual Electrical Characteristics (Ta = 25°C)

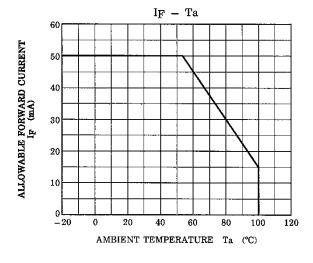
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
LED	Forward Voltage	VF	IF = 10mA	1.0	1.15	1.3	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5V	_	_	10	μΑ
	Capacitance	CT	V = 0 V, f = 1MHz	/_	10	-	pF
DETECTOR	Peak Off-State Current	IDRM	V <sub>DRM</sub> = 400V	(-)	10	100	nA
	Peak On-Stage Voltage	V <sub>TM</sub>	I <sub>TM</sub> = 100mA	1	) )1.7	3.0	V
	Holding Current	lн	(	)_   	0.6	-	mA
	Critical Rate of Rise of Off- State Voltage	dv / dt	V <sub>in</sub> = 120Vrms, Ta = 85°C (Fig.1)	200	500	1	V / μs
	Critical Rate of Rise of Commutating Voltage	dv / dt(c)	V <sub>in</sub> = 30Vrms, IT = 15mA (Fig.1)	> _	0.2	_	V / μs

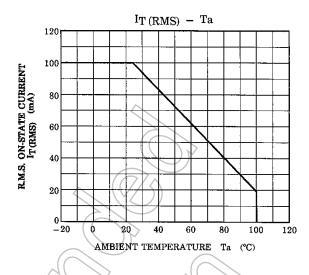
## Coupled Electrical Characteristics (Ta = $25^{\circ}$ C)

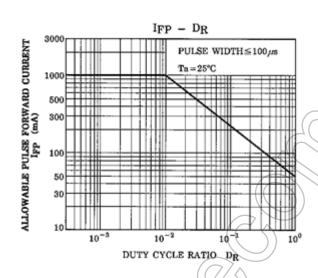
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	ТУР.	MAX	UNIT
Trigger LED Current	TLP3041(S)			7		15	
	TLP3042(S)	IFT	VT = 3V		5	10	mA
	TLP3043(S)				_	5	
Inhibit Voltage		VIH	IF = Rated IFT	) –	_	40	V
Leakage in Inhibited State	Э	IIH	IF = Rated IFT VT = Rated VDRM	_	100	300	μΑ
Capacitance Input to Outp	out	Cs	Vs = 0 V, f = 1MHz	_	0.8	_	pF
Isolation Resistance		Rs	V <sub>S</sub> = 500V (R.H. ≤ 60%)	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
Isolation Voltage		$\sim$	AC, 1 minute	5000	_	_	Vrms
		BVs	AC, 1 second (in oil)	_	10000	_	VIIIIS
			DC, 1 minute (in oil)	_	10000	_	Vdc

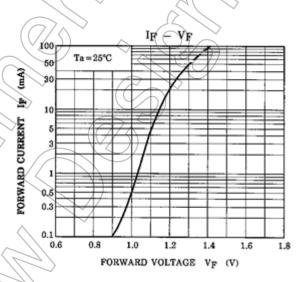
Fig. 1 dv / dt test circuit

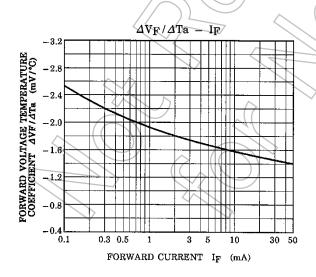


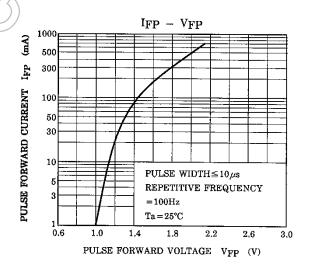




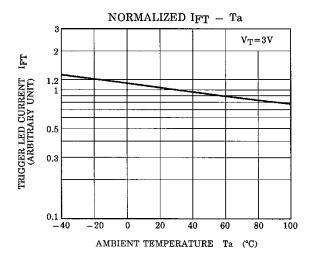


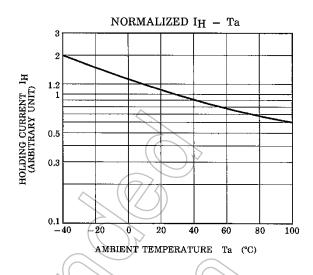


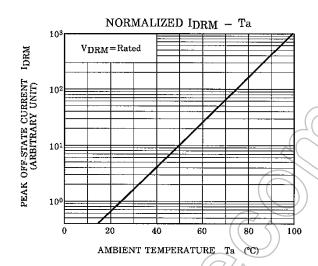


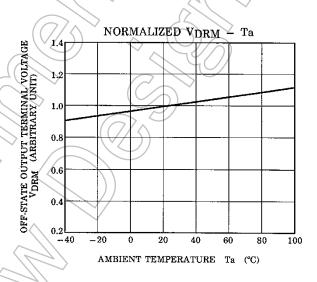


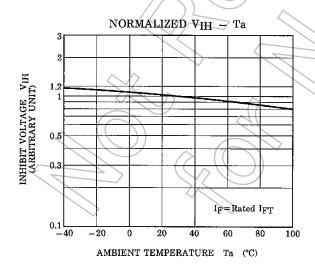
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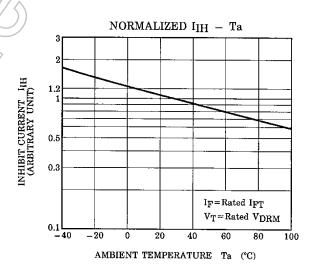












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